

Samsung M393A8G40AB2-CWE memory module

Artikel	115797
Herstellernummer	M393A8G40AB2-CWE
EAN	8592978250096
Samsung	



Proven DRAM module solution in the global market

Samsung's memory modules are designed for a wide range of applications to deliver the best performance with low power requirements.

Zusammenfassung

Proven DRAM module solution in the global market

Samsung's memory modules are designed for a wide range of applications to deliver the best performance with low power requirements.

Samsung M393A8G40AB2-CWE, 64 GB, 1 x 64 GB, DDR4, 3200 MHz, 288-pin DIMM

Samsung M393A8G40AB2-CWE. Component for: PC/Server, Internal memory: 64 GB, Memory layout (modules x size): 1 x 64 GB, Internal memory type: DDR4, Memory clock speed: 3200 MHz, Memory form factor: 288-pin DIMM, CAS latency: 24, ECC

Merkmale

Logistics data

Harmonized System (HS) code 84733020

Features

Buffered memory type	Registered (buffered)
CAS latency	24
Internal memory	64 GB
Memory layout (modules x size)	1 x 64 GB
Internal memory type	DDR4
Memory clock speed	3200 MHz
Component for	PC/Server
Memory form factor	288-pin DIMM
ECC	Yes
Memory ranking	2
Memory voltage	1.2 V

Preisänderungen und Irrtümer vorbehalten. Alle Produkte solange der Vorrat reicht.